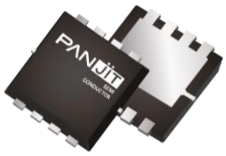
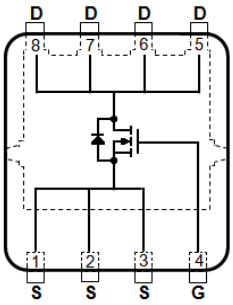
PJQ4466AP

60V N-Channel Enhancement Mode MOSFET

Voltage	60 V	Current	33 A

DFN3333-8L





Features

- $R_{DS(ON)}$, V_{GS}@10V, I_D@15A<21mΩ
- $R_{DS(ON)}$, V_{GS}@4.5V, I_D@8A<24mΩ
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	60	V
Gate-Source Voltage		V_{GS}	±20	
Continuous Drain Current	T_C=25°C	I_D	33	A
	T_C=100°C		21	
Pulsed Drain Current(Note 1)	T_C=25°C	I_{DM}	132	
Power Dissipation	T_C=25°C	P_D	44.6	W
	T_C=100°C		18	
Continuous Drain Current	T_A=25°C	I_D	6	A
	T_A=70°C		5	
Power Dissipation	T_A=25°C	P_D	2.0	W
Power Dissipation	T_A=70°C		1.3	
Single Pulse Avalanche Energy(Note 6)		E_{AS}	42	mJ
Operating Junction and Storage Temperature Range		T_J,T_{STG}	-55~150	°C
Typical Thermal Resistance(Note 4,5)	Junction to Case	$R_{\theta JC}$	2.8	°C/W
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature

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Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=250uA	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS}, I_D=250uA	1.0	1.73	2.5	
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS}=10V, I_D=15A	-	18	21	mΩ
		V_{GS}=4.5V, I_D=8A	-	21	24	
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=60V, V_{GS}=0V	-	-	1.0	uA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±20V, V_{DS}=0V	-	-	±100	nA
Dynamic(Note 5)						
Total Gate Charge	Q_g	V_{DS}=30V, I_D=15A, V_{GS}=10V(Note 1,2)	-	28	-	nC
Gate-Source Charge	Q_{gs}		-	3.5	-	
Gate-Drain Charge	Q_{gd}		-	6.5	-	
Input Capacitance	Ciss	V_{DS}=20V, V_{GS}=0V, f=1.0MHZ	-	1680	-	pF
Output Capacitance	Coss		-	115	-	
Reverse Transfer Capacitance	Crss		-	85	-	
Turn-On Delay Time	$td_{(on)}$	V_{DD}=30V, I_D=1A, V_{GS}=10V, R_G=6Ω (Note 1,2)	-	7.2	-	ns
Turn-On Rise Time	t_r		-	38	-	
Turn-Off Delay Time	$td_{(off)}$		-	34	-	
Turn-Off Fall Time	t_f		-	8.2	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	33	A
Reverse Recovery Time	V_{SD}	I_S=1A, V_{GS}=0V	-	0.68	1	V

NOTES :

1. Pulse width≤300us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}$=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
4. The maximum current rating is package limited.
5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch^2 with 2oz.square pad of copper.
6. The test condition is L=0.1mH, I_{AS}=29A, V_{DD}=25V, V_{GS}=10V, Starting T_J=25°C.
7. Guaranteed by design, not subject to production testing.

PJQ4466AP

TYPICAL CHARACTERISTIC CURVES

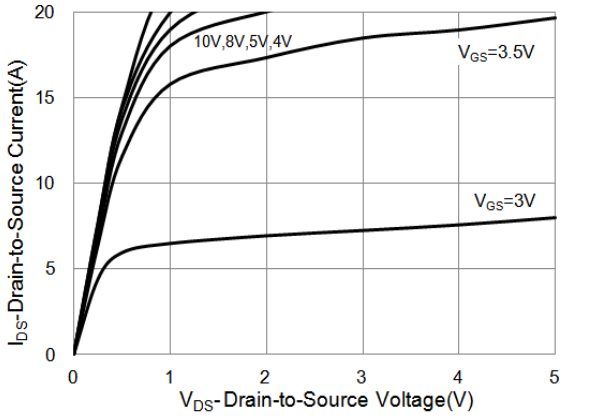

Fig.1 On-Region Characteristics

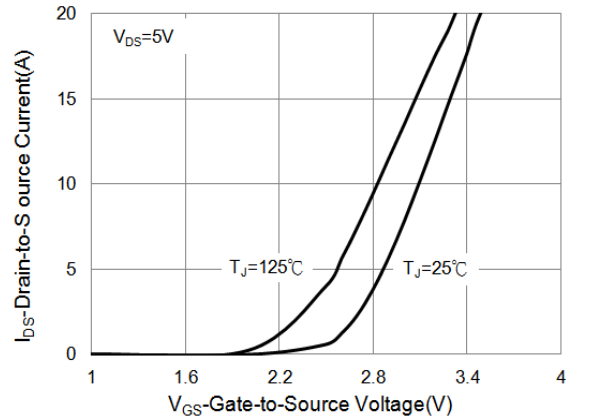

Fig.2 Transfer Characteristics

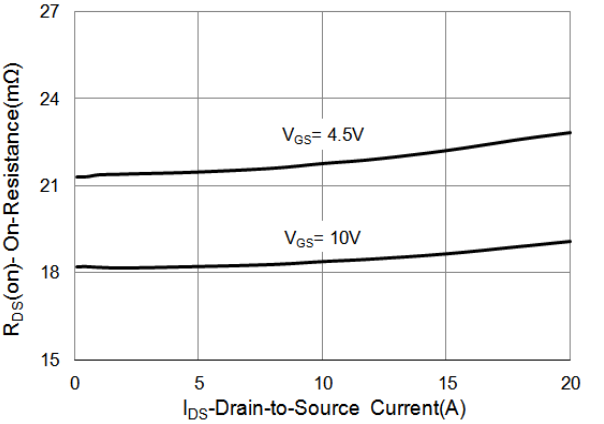

Fig.3 On-Resistance vs. Drain Current

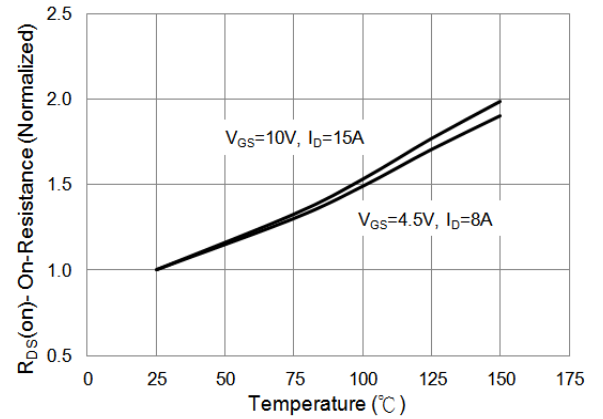

Fig.4 On-Resistance vs. Junction temperature

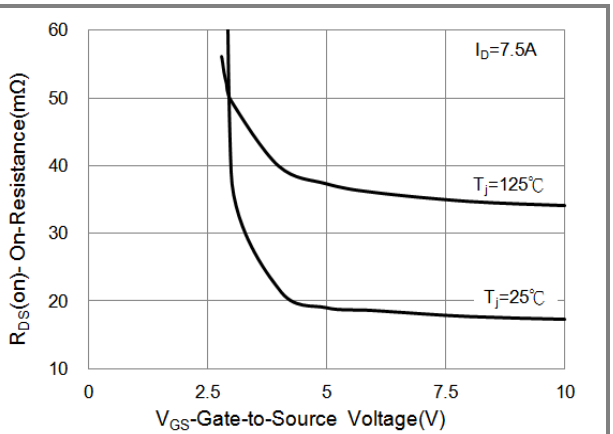

Fig.5 On-Resistance Variation with V_{GS}

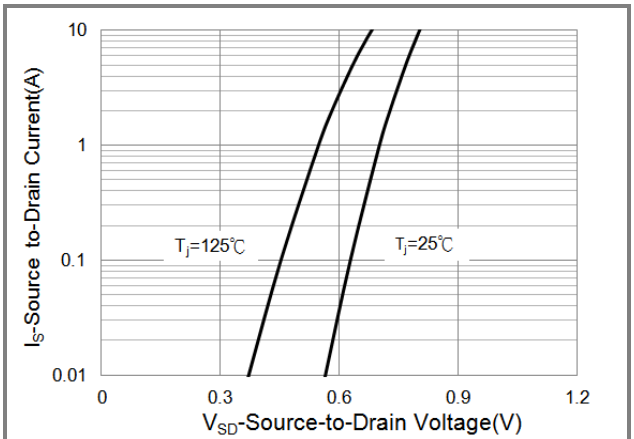

Fig.6 Source-Drain Diode Forward Voltage

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TYPICAL CHARACTERISTIC CURVES

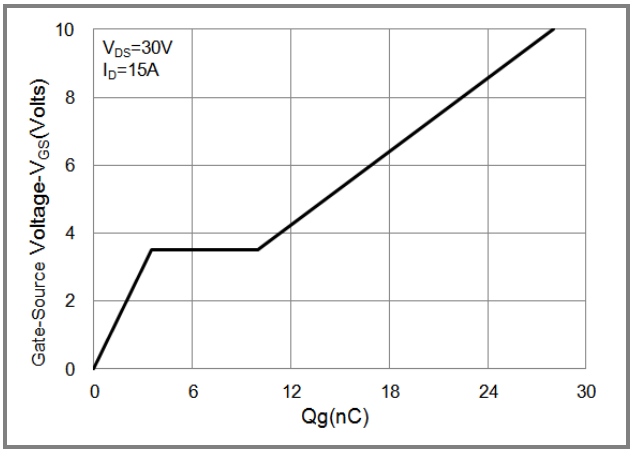


Fig.7 Gate-Charge Characteristics

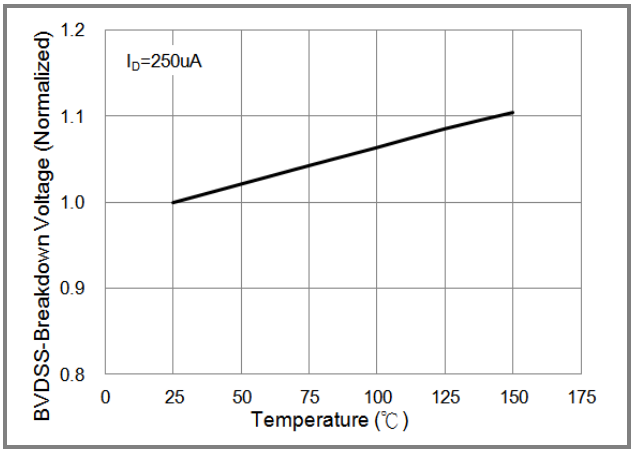


Fig.8 Breakdown Voltage Variation vs. Temperature

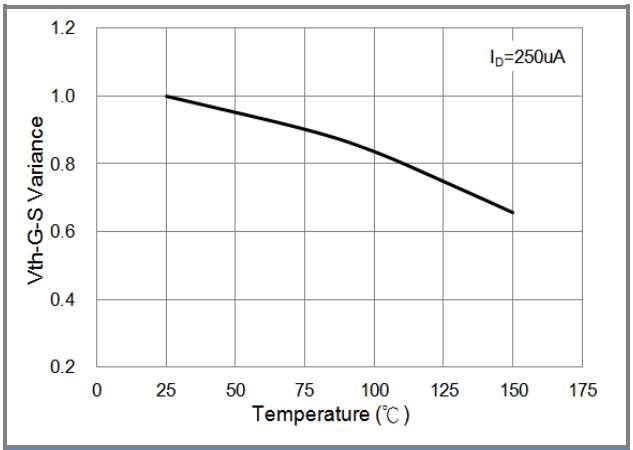


Fig.9 Threshold Voltage Variation with Temperature

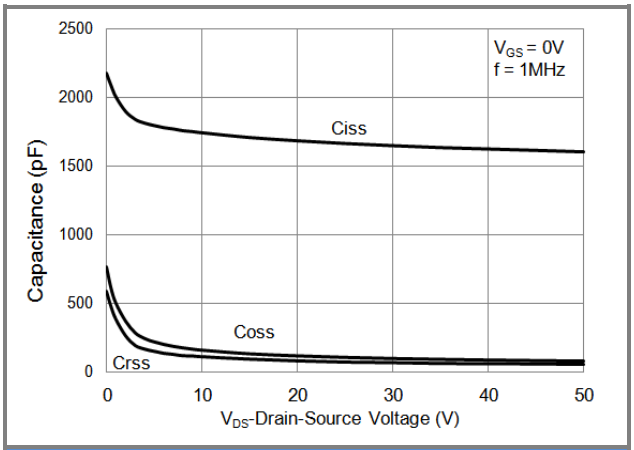


Fig.10 Capacitance vs. Drain-Source Voltage

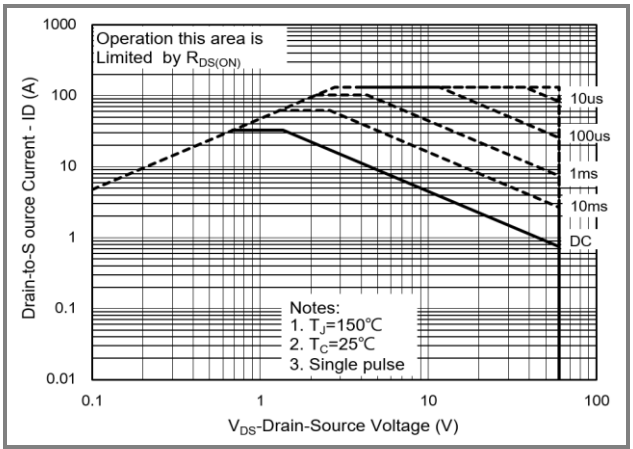


Fig.11 Maximum Safe Operating Area

PJQ4466AP

TYPICAL CHARACTERISTIC CURVES

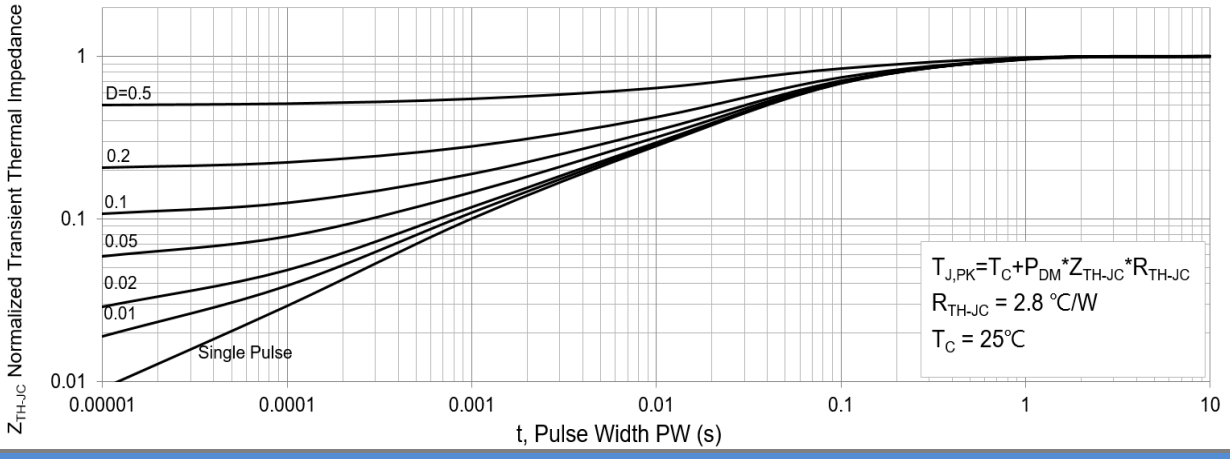


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

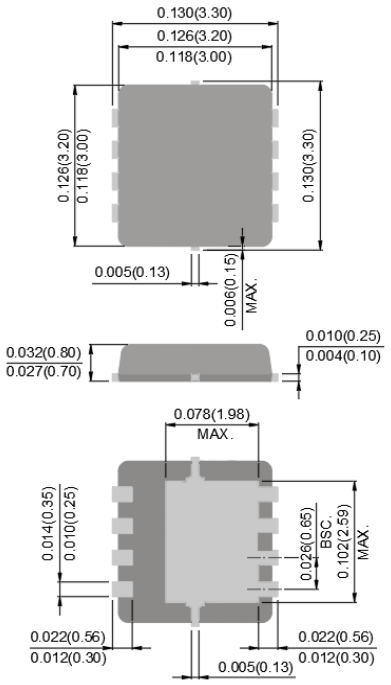
PJQ4466AP

Part No. Packing Code Version

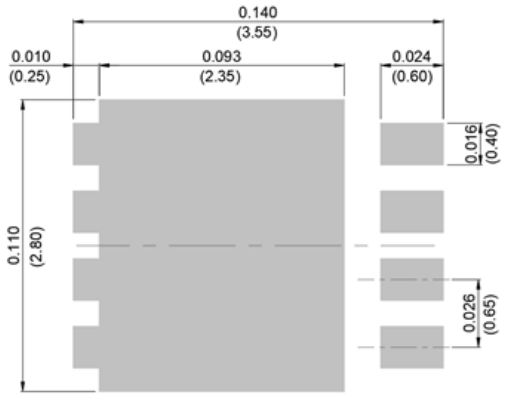
Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4466AP_R2_00001	DFN3333-8L	5K pcs / 13” reel	4466	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout

DFN3333-8L Dimension — Unit: inch(mm)



DFN3333-8L Pad Layout — Unit: inch(mm)



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